

PHYSICAL REVIEW B

CONDENSED MATTER

THIRD SERIES, VOLUME 55, NUMBER 7

CONTENTS

15 FEBRUARY 1997-I

BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Einstein relations near the metal-insulator transition	4003
T. G. Castner	
Density of states of InI: Theoretical and experimental investigation	4007
M. I. Kolinko	
Generalized Gutzwiller method for $n \geq 2$ correlated bands: First-order metal-insulator transitions	4011
J. Bünnemann and W. Weber	
Spectral function of small spin polaron in two-dimensional spherically symmetric antiferromagnetic state	4015
A. F. Barabanov, R. O. Kuzian, and L. A. Maksimov	
Influence of electron-electron scattering on the electrical resistivity caused by oriented line imperfections	4019
M. L. Huberman and A. W. Overhauser	
Discrepancies between infrared and dc resistivities of $\text{La}_{0.7}\text{Ca}_{0.3}\text{MnO}_3$ samples	4023
K. H. Kim, J. Y. Gu, H. S. Choi, D. J. Eom, J. H. Jung, and T. W. Noh	

Semiconductors I: bulk

Influence of electron correlations on ground-state properties of III-V semiconductors	4027
Simon Kalvoda, Beate Paulus, Peter Fulde, and Hermann Stoll	
Interferometric four-wave-mixing spectroscopy on bulk GaAs	4031
M. U. Wehner, J. Hetzler, and M. Wegener	
Evidence for muonium passivation in n -doped Ge	4035
R. Kadono, R. M. Macrae, K. Nishiyama, and K. Nagamine	
Rhombohedral C_{60} polymer: A semiconducting solid carbon structure	4039
Susumu Okada and Susumu Saito	
Inverted order of acceptor and donor levels of the Si-related DX center in $\text{Al}_x\text{Ga}_{1-x}\text{As}$	4042
Subhasis Ghosh and Vikram Kumar	
Diffraction pattern of a defect: Two-dimensional angular correlation of positron-annihilation radiation studies of defects in semiconductors	4046
T. McMullen and Marilyn F. Bishop	
Optically enhanced NMR of plastically deformed GaAs	4050
T. Pietraß, A. Bifone, J. Krüger, and J. A. Reimer	

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Formation of quantum dots in twofold cleaved edge overgrowth	4054
M. Grundmann and D. Bimberg	
Exact density of states of a two-dimensional electron gas in a strong magnetic field and a long-range correlated random potential	4057
Lothar Spies, Walter Apel, and Bernhard Kramer	
Electron-electron interaction in a narrow, disordered electron gas in nonequilibrium	4061
H. Linke, P. Omling, Hongqi Xu, and P. E. Lindelof	
Persistent currents from the competition between Zeeman coupling and spin-orbit interaction	4065
Tie-Zheng Qian, Ya-Sha Yi, and Zhao-Bin Su	

(Continued)

Aharonov-Bohm-type oscillations of thermopower in a quantum-dot ring geometry	4069
Ya. M. Blanter, C. Bruder, Rosario Fazio, and Herbert Schoeller	
Properties of the single-electron box at arbitrary temperature	4073
Xiaohui Wang	
Critical conductivity of the quantum Hall system at higher Landau levels	4077
Takamichi Terao	
Line shape of resonant tunneling between fractional quantum Hall edges	4081
I. J. Maasilta and V. J. Goldman	
Insulator-to-quantum-Hall-liquid transition in an antidot lattice	4085
F. Nihey, M. A. Kastner, and K. Nakamura	
Spin-reversed quasielectron excitations in the $\frac{2}{3}$ -filling fractional-quantum-Hall-effect state	4089
S. I. Dorozhkin, M. O. Dorokhova, R. J. Haug, and K. Ploog	
Vibronic model for band A emission in diamond	4093
Suman B. Iyer, G. Ananthakrishna, Brij M. Arora, and J. Chandrasekhar	
Defect modes of stratified dielectric media	4097
Nian-hua Liu	
Ag on Au/Si(111): Interfacial interactions on a submicrometer scale	4101
A. Kolmakov, J. Kovac, S. Günther, L. Casalis, L. Gregoratti, M. Marsi, and M. Kiskinova	

Surface physics, low-dimensional systems, and related topics

Kinetics of rapid reactions on nanometer catalyst particles	4105
V. P. Zhdanov and B. Kasemo	
Temperature and momentum dependence of the spectral function of the charge-density wave and of the normal α phase of Pb/Ge(111)	4109
A. Goldoni, C. Cepek, and S. Modesti	
Conduction through single Mg and Na atoms linking two macroscopic electrodes	4113
N. D. Lang	
Bulk and surface $4f$ states of Gd	4117
R. F. Sabiryanov and S. S. Jaswal	
Peak rotation in photoelectron diffraction patterns by circularly polarized light	4120
A. Chassé and P. Rennert	

ARTICLES**Electronic structure: wide-band, narrow-band, and strongly correlated systems**

Optical properties and electronic structures of Ni ₃ Al alloys	4124
Joo Yull Rhee, B. N. Harmon, and D. W. Lynch	
<i>Ab initio</i> theoretical comparative study of magnetic coupling in KNiF ₃ and K ₂ NiF ₄	4129
Ibério de P. R. Moreira and Francesc Illas	
Three-particle approximation for transition-metal oxides	4138
J. Lægsgaard and A. Svane	
Magnetic correlations in the two-dimensional Anderson-Hubbard model	4149
M. Ulmke and R. T. Scalettar	
Lattice distortion in Cu-based dilute alloys: A first-principles study by the KKR Green-function method	4157
N. Papanikolaou, R. Zeller, P. H. Dederichs, and N. Stefanou	
Generalized Slater-Koster method for fitting band structures	4168
M. D. Stiles	
Electronic structure and binding energies of hydrogen-decorated vacancies in Ni	4174
H. Zheng, B. K. Rao, S. N. Khanna, and P. Jena	

Spin-0 soliton formation in spin-Peierls systems: Charge-transfer complexes DAP-TCNQ and DAP-DMTCNQ	4182
Taro Sekikawa, Hiroshi Okamoto, Tadaoki Mitani, Tamotsu Inabe, Yusei Maruyama, and Takayoshi Kobayashi	
Electronic-transport studies of the organic metals α -(BETS) ₂ NH ₄ Hg(SCN) ₄ and α -(BETS) ₂ KHg(SCN) ₄ in high magnetic fields, where BETS is bis(ethylenedithio)tetraselenafulvalene	4191
S. A. Ivanov, C. H. Mielke, T. Coffey, D. A. Howe, C. C. Agosta, B. W. Fravel, and L. K. Montgomery	
Fermi surface and magnetic phases of the low-carrier-density strongly correlated electron system CeP	4197
T. Terashima, S. Uji, H. Aoki, W. Joss, Y. Haga, A. Uesawa, and T. Suzuki	
Variation of electronic structure in La _{1-x} Sr _x MnO ₃ (0 ≤ x ≤ 0.3) as investigated by optical conductivity spectra	4206
Y. Okimoto, T. Katsufuji, T. Ishikawa, T. Arima, and Y. Tokura	
Scaling of the conductivity of Si:B: Anomalous crossover in a magnetic field	4215
S. Bogdanovich, Peihua Dai, M. P. Sarachik, V. Dobrosavljevic, and G. Kotliar	
Specific heat of Si:(P,B) at low temperatures	4219
S. Wagner, M. Lakner, and H. v. Löhneysen	
LEED and photoemission study of the stability of VO ₂ surfaces	4225
E. Goering, M. Schramme, O. Müller, R. Barth, H. Paulin, M. Klemm, M. L. denBoer, and S. Horn	
Coherent and dissipative dc transport in quasi-one-dimensional systems of coupled polyaniline chains	4231
R. Hey, F. Gagel, M. Schreiber, and K. Maschke	
Ionization of the surface-state electron by half-cycle electric-field pulses	4238
T. F. Jiang	
Resonant inelastic soft-x-ray scattering from valence-band excitations in 3d ⁰ compounds	4242
S. M. Butorin, J.-H. Guo, M. Magnuson, and J. Nordgren	
Nonequilibrium electron distribution in metals	4250
D. Bejan and G. Raşeev	
Electronic structure and temperature-induced paramagnetism in LaCoO ₃	4257
T. Saitoh, T. Mizokawa, A. Fujimori, M. Abbate, Y. Takeda, and M. Takano	
Electronic structure of the organic conductor α -(BEDT-TTF) ₂ I ₃ studied by angle-resolved and core-level photoelectron spectroscopy	4267
S. Söderholm, R. T. Girard, and D. Schweitzer	
Ions in crystals: The topology of the electron density in ionic materials. I. Fundamentals	4275
A. Martín Pendás, Aurora Costales, and Víctor Luña	
Ions in crystals: The topology of the electron density in ionic materials. II. The cubic alkali halide perovskites	4285
Víctor Luña, Aurora Costales, and A. Martín Pendás	
Photonic band structures of two-dimensional systems fabricated from rods of a cubic polar crystal	4298
V. Kuzmiak, A. A. Maradudin, and A. R. McGurn	

Semiconductors I: bulk

Correlation of electrical and optical properties of the vanadium-related <i>C</i> level in silicon	4312
R. Pässler, H. Pettersson, H. G. Grimmeiss, and K. Schmalz	
Defect formation during deposition of undoped <i>a</i> -Si:H by rf glow discharge	4323
Keiji Maeda, Ikurou Umez, and Hotaka Ishizuka	
Angular dependence of the electronic energy loss of 800-keV He ions along the Si(100) direction	4332
J. H. R. dos Santos, P. L. Grande, M. Behar, H. Boudinov, and G. Schiwietz	
Optical functions of semiconductors beyond density-functional theory and random-phase approximation	4343
V. I. Gavrilenko and F. Bechstedt	
Exact parameter relations and effective masses within <i>sp</i> ³ zinc-blende tight-binding models	4353
J. P. Loehr and D. N. Talwar	
Hole scattering and optical transitions in wide-band-gap nitrides: Wurtzite and zinc-blende structures	4360
Yu. M. Sirenko, J. B. Jeon, B. C. Lee, K. W. Kim, M. A. Littlejohn, M. A. Strosio, and G. J. Iafrate	

Binding energy of the free exciton in indium arsenide	4376
P. J. P. Tang, M. J. Pullin, and C. C. Phillips	
Excited states of Fe^{3+} in GaN	4382
R. Heitz, P. Maxim, L. Eckey, P. Thurian, A. Hoffmann, I. Broser, K. Pressel, and B. K. Meyer	
Theory of acceptor-ground-state description and hot photoluminescence in cubic semiconductors	4388
A. V. Malyshev, I. A. Merkulov, and A. V. Rodina	
Concentration dependence of the exchange interaction in $\text{Pb}_{1-x}\text{Eu}_x\text{Te}$	4400
M. Górska, J. R. Anderson, J. L. Peng, Y. Oka, J. Y-Jen, I. Mogi, D. Ravot, and Z. Gołacki	
Optical transitions in cubic $\text{HgSe}_{1-y}\text{S}_y$ crystals	4405
E. Guziewicz, B. J. Kowalski, K. Szamota-Sadowska, W. Szuszkiewicz, and B. A. Orlowski	
Photoluminescence from metastable states in long-range ordered $(\text{Al}_{0.5}\text{Ga}_{0.5})_{0.51}\text{In}_{0.49}\text{P}$	4411
Kenichi Yamashita, Takashi Kita, Hiroshi Nakayama, and Taneo Nishino	
Iron group impurities in $\beta\text{-FeSi}_2$ studied by EPR	4417
K. Irmischer, W. Gehlhoff, Y. Tomm, H. Lange, and V. Alex	
Chemical (dis)order in $\alpha\text{-Si}_{1-x}\text{C}_x\text{:H}$ for $x < 0.6$	4426
P. I. Rovira and F. Alvarez	

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Adsorption of elemental S on $\text{Si}(100)2 \times 1$: Surface restoration	4435
Aris Papageorgopoulos, Adero Corner, M. Kamaratos, and C. A. Papageorgopoulos	
Resonant guided elastic waves in an adsorbed bilayer: Theoretical analysis of the density of states	4442
E. H. El Boudouti, B. Djafari-Rouhani, and A. Akjouj	
Excitonic properties of zinc-blende ZnSe/MgS superlattices studied by reflection spectroscopy	4449
Hidekazu Kumano, Hiroyuki Nashiki, Ikuo Suemune, Munetaka Arita, Toshio Obinata, Hideki Suzuki, Katsuhiro Uesugi, and Jun'ichiro Nakahara	
Microphotoluminescence studies of single quantum dots. I. Time-resolved experiments	4456
U. Bockelmann, W. Heller, A. Filoramo, and Ph. Roussignol	
Microphotoluminescence studies of single quantum dots. II. Magnetic-field experiments	4469
U. Bockelmann, W. Heller, and G. Abstreiter	
Carrier relaxation dynamics in quantum dots: Scattering mechanisms and state-filling effects	4473
S. Grosse, J. H. H. Sandmann, G. von Plessen, J. Feldmann, H. Lipsanen, M. Sopanen, J. Tulkki, and J. Ahopelto	
Pressure dependence of band offsets in $\text{InAs/Ga}_{1-x}\text{In}_x\text{Sb}$ superlattices	4477
Hyeonsik M. Cheong, William Paul, Michael E. Flatté, and Richard H. Miles	
Magnetoresistance in a back-gated surface superlattice	4482
A. Soibel, U. Meirav, D. Mahalu, and Hadas Shtrikman	
From Landau levels to universal fluctuations: Level statistics for lateral superlattices	4486
O. Steffens, M. Suhrke, and P. Rotter	
Generalized two-dimensional mesoscopic quantum transport: Application to disordered quantum wires	4494
I. Vurgaftman and J. R. Meyer	
Excitons in strained $(\text{Ga,In})\text{Sb/GaSb}$ quantum wells	4503
N. Bertru, O. Brandt, R. Klann, A. Mazuelas, W. Ulrici, and K. H. Ploog	
Exchange instabilities in semiconductor double-quantum-well systems	4506
Lian Zheng, M. W. Ortolano, and S. Das Sarma	
Change of symmetry of the barrier D^- ground state in finite magnetic fields	4516
Sadayoshi Kanamaru and Naoki Tokuda	
Heat generation by electric current in nanostructures	4522
V. L. Gurevich	
Spontaneous charge polarization in single-electron tunneling through coupled nanowires	4530
A. A. Tager, J. M. Xu, and M. Moskovits	

(Continued)

Shot noise in resonant-tunneling structures	4539
G. Iannaccone, M. Macucci, and B. Pellegrini	
Statistical properties of the low-temperature conductance peak heights for Corbino disks in the quantum Hall regime	4551
N. R. Cooper, B. I. Halperin, Chin-Kun Hu, and I. M. Ruzin	
Series of magnetoresistance oscillations of a two-dimensional electron gas in a strong periodic magnetic modulation	4558
Q. W. Shi and K. Y. Szeto	
Photoluminescence properties of silicon quantum-well layers	4563
P. N. Saeta and A. C. Gallagher	
Role of interactions in the energy-loss hopping and recombination of two-dimensional electrons and holes	4575
J. E. Golub, S. D. Baranovskii, and P. Thomas	
Magnetic-field effects on one- and two-hole states in parabolic quantum dots	4580
F. B. Pedersen and Yia-Chung Chang	
Band alignments and offsets in In(As,Sb)/InAs superlattices	4589
Y. B. Li, D. J. Bain, L. Hart, M. Livingstone, C. M. Ciesla, M. J. Pullin, P. J. P. Tang, W. T. Yuen, I. Galbraith, C. C. Phillips, C. R. Pidgeon, and R. A. Stradling	
Static and high-frequency electric fields in silicon MOS and MS structures probed by optical second-harmonic generation	4596
C. Ohlhoff, G. Lüpke, C. Meyer, and H. Kurz	
Magnetorefectivity of $\text{Pb}_{1-x}\text{Eu}_x\text{Te}$ epilayers and $\text{PbTe}/\text{Pb}_{1-x}\text{Eu}_x\text{Te}$ multiple quantum wells	4607
Shu Yuan, Heinz Krenn, Gunther Springholz, Yukio Ueta, Günther Bauer, and Patrick J. McCann	
Femtosecond coherent polariton dynamics in the layered III-VI semiconductor InSe	4620
S. Nüsse, P. Haring Bolivar, H. Kurz, F. Levy, A. Chevy, and O. Lang	
Magnetoluminescence study of n -type modulation-doped $\text{ZnSe}/\text{Zn}_x\text{Cd}_{1-x}\text{Se}$ quantum-well structures	4628
G. Kioseoglou, J. Haetty, H. C. Chang, H. Luo, A. Petrou, T. Schmiedel, and Pawel Hawrylak	
Origin of sharp lines in photoluminescence emission from submonolayers of InAs in GaAs	4633
C. A. Tran, R. A. Ares, V. A. Karasyuk, S. P. Watkins, G. Letourneau, and R. Leonelli	
Precise solution to a model of the kinetic equation	4639
I. I. Boiko and A. L. Chudnovskiy	
Random impurity and phonon-scattering processes in multibarrier structures	4645
A. N. Khondker and A. Haque	
<i>Ab initio</i> derived kinetic Monte Carlo model of H_2 desorption from $\text{Si}(100)\text{-}2\times 1$	4649
Michelle R. Radeke and Emily A. Carter	
Local arrangement of silylene groups on $\text{Si}(100)2\times 1$ after SiH_4 decomposition	4659
J. Spitzmüller, M. Fehrenbacher, M. Pitter, H. Rauscher, and R. J. Behm	
Quantum confinement of edge states in Si crystallites	4665
Shang Yuan Ren	
Polaron effects in asymmetric semiconductor quantum-well structures	4670
Jun-jie Shi, Xiu-qin Zhu, Zi-xin Liu, Shao-hua Pan, and Xing-yi Li	
Subbands, exchange, and correlation effects on collective excitations in parabolic-quantum-well wires	4680
Antonio Newton Borges, Salviano A. Leão, and Oscar Hipólito	
Edge and strip plasmons in a two-dimensional electron fluid	4684
S. Rudin and M. Dyakonov	
Yellow luminescence and related deep states in undoped GaN	4689
E. Calleja, F. J. Sánchez, D. Basak, M. A. Sánchez-García, E. Muñoz, I. Izpura, F. Calle, J. M. G. Tijero, J. L. Sánchez-Rojas, B. Beaumont, P. Lorenzini, and P. Gibart	
Voltage-probe and imaginary-potential models for dephasing in a chaotic quantum dot	4695
P. W. Brouwer and C. W. J. Beenakker	
Quantum waveguide transport with side-branch structures: A recursive algorithm	4703
Ji-Rong Shi and Ben-Yuan Gu	

Deviations from the Gaussian distribution of mesoscopic conductance fluctuations	4710
M. C. W. van Rossum, Igor V. Lerner, Boris L. Altshuler, and Th. M. Nieuwenhuizen	

Surface physics, low-dimensional systems, and related topics

Unusual disordering processes of oxygen overlayers on Rh(111): A combined diffraction study using thermal He atoms and low-energy electrons	4717
H. Over, S. Schwegmann, D. Cvetko, V. De Renzi, L. Floreano, R. Gotter, A. Morgante, M. Peloi, F. Tommasini, and S. Zennaro	
Room temperature growth of submonolayers of silicon on Si(001) studied with scanning tunneling microscopy	4723
J. van Wingerden, A. van Dam, M. J. Haye, P. M. L. O. Scholte, and F. Tuinstra	
Surface atomic geometry of Si(001)-(2×1): A low-energy electron-diffraction structure analysis	4731
H. Over, J. Wasserfall, W. Ranke, C. Ambiatello, R. Sawitzki, D. Wolf, and W. Moritz	
Adatom-step interactions: Atomistic simulations and elastic models	4737
L. E. Shilkrot and D. J. Srolovitz	
van der Waals interaction between a molecule and a spherical cavity in a metal: Nonlocality and anisotropy effects	4745
B. Labani, M. Boustimi, and J. Baudon	
Vibrational analysis of the 1×1-O overlayer on Ru(0001)	4751
P. He and K. Jacobi	
Molecular-orbital study of Li and LiOH adsorption on a Cu(001) surface. II. Cluster-model calculations with image charges	4755
Tomonari Sumi, Yoshiko Sakai, and Eisaku Miyoshi	
Interaction of hydrogen with transition metal fcc(111) surfaces	4761
R. Löber and D. Hennig	
Infrared and Raman studies of pressure-polymerized C ₆₀	4766
A. M. Rao, P. C. Eklund, J-L. Hodeau, L. Marques, and M. Nunez-Regueiro	
Light emission from surface plasmon polaritons mediated by metallic fine particles	4774
T. Kume, S. Hayashi, and K. Yamamoto	
Interband absorption of Ru studied by optical absorption of continuous thin films and small particles	4783
E. Anno and T. Yamaguchi	
Theoretical study of the valence-level photoemission spectrum of C ₆ H ₆ adsorbed on Ni, Pd, and Pt metal surfaces	4787
M. Ohno and W. von Niessen	
Growth of ordered domains in a highly anisotropic two-dimensional system	4797
O. M. Braun, M. V. Paliy, and M. Peyrard	
Dependence of inner-shell vacancy production upon distance in hard Li-Al collisions	4811
John W. Hartman, M. H. Shapiro, T. A. Tombrello, and J. A. Yarmoff	
Thin films of the charge-density-wave oxide Rb _{0.30} MoO ₃ by pulsed-laser deposition	4817
O. C. Mantel, H. S. J. van der Zant, A. J. Steinfort, C. Dekker, C. Træholt, and H. W. Zandbergen	
Theory of atom transfer with a scanning tunneling microscope	4825
Shiwu Gao, M. Persson, and B. I. Lundqvist	

Errata

Erratum: Interactions between adsorbed Si dimers on Si(001) [Phys. Rev. B 54 , 1557 (1996)]	4837
A. van Dam, J. van Wingerden, M. J. Haye, P. M. L. O. Scholte, and F. Tuinstra	

Cumulative Author Index	4838
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